Your Voice Matters eBeam Initiative 2015 Survey





Thank you to the 64 luminaries and members for your responses (35 companies represented)

Vote of Confidence in Multi-beam for Masks



HVM Multi-beam Prediction – Late 2018 Weighted average slips 6 months from 2014 Survey





Mask Makers More Optimistic on 2018 HVM 96% Mask vs 65% Equipment Makers say by 2018

By the end of which year do you believe that multi-beam technology will be used for high volume manufacturing mask writing? Select one answer. 60% 52% Equipment Makers (all types) 50% % of Respondents Mask Makers 40% 35% 35.3% 30% 30% 96% mask 18% 20% vs 65% 12% 13% equip. say by 2018 10% 4% 0% N=17 Equipment 2019 or later 2016 2017 2018 N=23 Mask Year

⊰eam

Initiative

Purchasing Predictions for Multi-beam >50% by 2020





Lithography Perceptions Favor EUV 62% confidence in EUV





Optimism in EUV Increased vs 2014 Respondents answering "Never" down to 15%





EUV to Drive 3D Mask Effects





Complex Mask Shapes Predicted for EUV



How much will CAD shapes on EUV masks differ from CAD shapes for wafer printing due to OPC, shadow/flare correction, or eBeam mid-range scatter correction? Please select one.



- Curvilinear shape modulation
- Complex shape modulation
- Simple rectilinear shape modulation
- Only biasing and scaling. No shape modulation.
- None of the above.

Voicing Your Interests for 2016: Multi-beam for Mask, Inspection and CEBL





The Mask Maker Survey 2015



- Members requested the eBeam Initiative to "fill the gap" which the SEMATECH survey had served through 2013
 - Thanks to Matt Malloy, SUNY Poly SEMATECH, for his advice
 - This survey did not replicate the past ones
- Thank you to the 8 participating mask makers:
 - AMTC, DNP, GLOBALFOUNDRIES (IBM), HOYA, Photronics, Samsung, SMIC, Toppan



Masks per Mask Set Continue to Grow Long term 13% per ground rule



TAT Increases at Smaller Geometries





2015 Mask Shop Statistics Q3 2014 through Q2 2015



Data	Average	Range	Median
Average mask write time (hours)	9.6	4-16	7
Longest mask write time (hours)	32.7	18-72	29
Average data file size for single mask layer (Gbytes)	38	3-100	20
Largest data file size for single mask layer (Gbytes)	343	55-800	250
Median # of mask defects <0.5µm at 40nm production logic nodes & below	17.7	3-69.7	5.5
% of 40nm & below production masks rewritten	6.8%	1-10%	7%
First repair success rate production masks	86.9%	60-99%	92.5%
Slowest resist used for production (μ C/cm ²)	43.9	20.1-55	40
Max relative dose assigned to shots (1=nominal)	1.5x	1, 1.2x-3x	1.25x

75% Plan to Use >1 Dose in 2017





Range of Resists Predicted to Expand







Complexity Grows for the Mask Maker

- Longer write times and larger mask sets
- Dose modulation is here today
- EUV masks will have complex shapes
- Multi-beam for mask writing is much anticipated



Thank you to those who participated in the survey!

Feedback and questions for future surveys welcome – send to jan@williscalibra.com